TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

# 2SC2240

#### Low Noise Audio Amplifier Applications

The 2SC2240 is a transistor for low frequency and low noise applications. This device is designed to lower noise figure in the region of low signal source impedance, and to lower the pulse noise. This is recommended for the first stages of Equalizer amplifiers.

• Low noise: NF = 4dB (typ.)  $R_G$  = 100  $\Omega$ ,  $V_{CE}$  = 6 V,  $I_C$  = 100  $\mu A$ , f = 1 kHz : NF = 0.5dB (typ.)  $R_G$  = 1 k $\Omega$ ,  $V_{CE}$  = 6 V,  $I_C$  = 100  $\mu A$ , f = 1 kHz

• Low pulse noise: Low 1/f noise

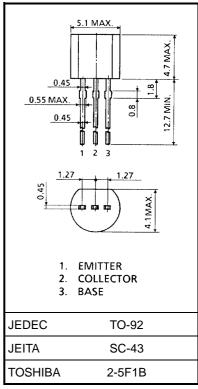
• High DC current gain:  $h_{FE} = 200 \sim 700$ 

• High breakdown voltage: VCEO = 120 V

#### Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	120	V
Collector-emitter voltage	V <sub>CEO</sub>	120	V
Emitter-base voltage	V <sub>EBO</sub>	5	V
Collector current	IC	100	mA
Base current	ΙΒ	20	mA
Collector power dissipation	PC	300	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C

Unit: mm



Weight: 0.21 g (typ.)

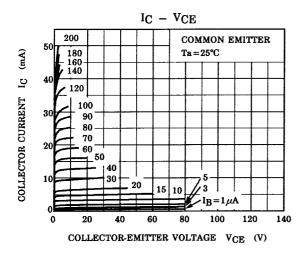


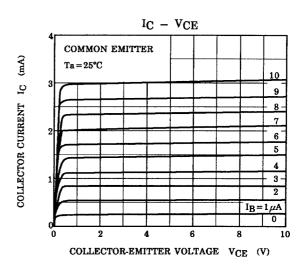
## Electrical Characteristics (Ta = 25°C)

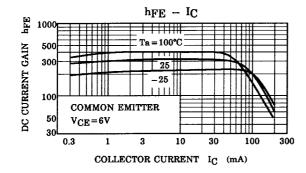
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = 120 \text{ V}, I_E = 0$	_	_	0.1	μΑ
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0	_	_	0.1	μΑ
Collector-emitter breakdown voltage	V (BR) CEO	$I_C = 1 \text{ mA}, I_B = 0$	120	_	_	V
DC current gain	h <sub>FE</sub> (Note)	V <sub>CE</sub> = 6 V, I <sub>C</sub> = 2 mA	200	_	700	
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 1 mA	_	_	0.3	V
Base-emitter voltage	V <sub>BE</sub>	$V_{CE} = 6 \text{ V}, I_{C} = 2 \text{ mA}$	_	0.65	_	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 6 V, I <sub>C</sub> = 1 mA	_	100	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	3.0	_	pF
Noise figure NF		$\begin{split} &V_{CE}=6 \text{ V, I}_{C}=0.1 \text{ mA, f}=10 \text{ Hz,} \\ &R_{G}=10 \text{ k}\Omega \end{split}$	_	_	6	dB
	NF	$\begin{aligned} &V_{CE}=6 \text{ V, I}_{C}=0.1 \text{ mA, f}=1 \text{ kHz,} \\ &R_{G}=10 \text{ k}\Omega \end{aligned}$	_	_	2	
		$\begin{aligned} &V_{CE}=6 \text{ V, I}_{C}=0.1 \text{ mA, f}=1 \text{ kHz,} \\ &R_{G}=100 \Omega \end{aligned}$		4		

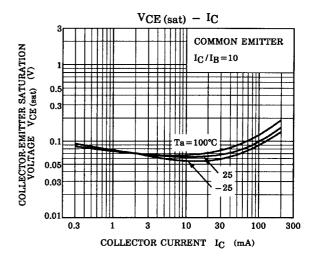
Note: hFE classification GR: 200~400, BL: 350~700

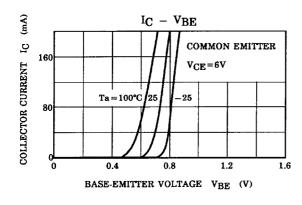
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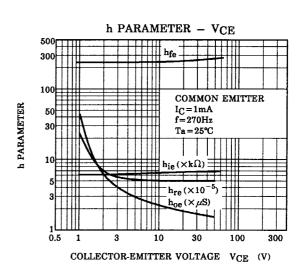


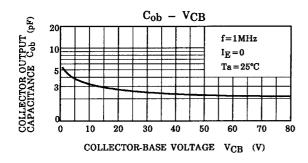


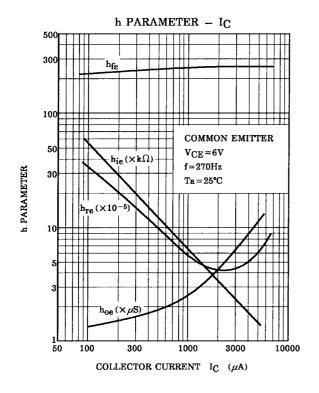


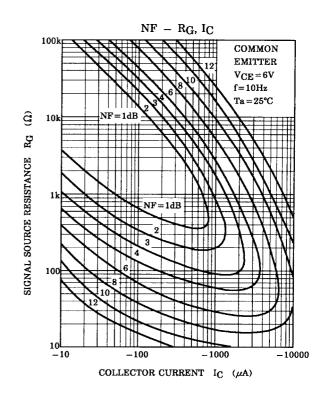


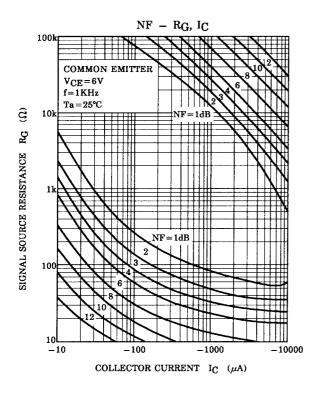


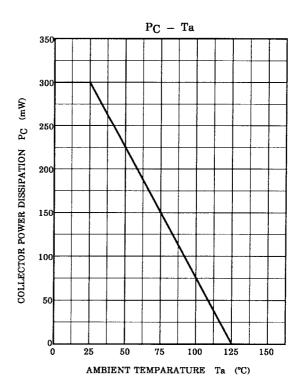












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